NSN 5961-00-501-1142

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-501-1142 **Inclosure Material:** Metal **Overall Length:** 0.340 inches **Overall Diameter:** 0.500 inches **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 330.0 nonrepetitive peak reverse voltage and 200.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 3.20 amperes source cutoff current preset and 3.20 amperes forward current, average **Power Rating Per Characteristic:** 0.5 watts small-signal input power, common-collector peak **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius case **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0